

530V NPN HIGH VOLTAGE POWER TRANSISTOR IN TO92

Features

- BV_{CEO} > 530V
- BV_{CES} > 900V
- BV_{EBO} > 10V
- I_C = 1.5A high Continuous Collector Current
- High Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

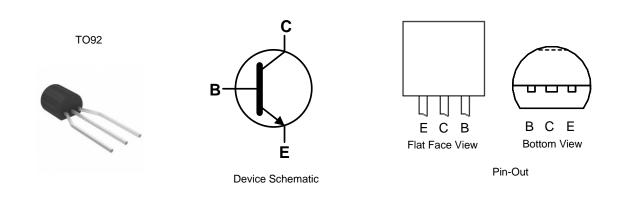
Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

Mechanical Data

- Case: TO92
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 3
- Weight: 200mg (Approximate)



Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13003NZTR-G1	TO92 (Joggled Legs)	13003NZ-G1	2,000 Taped, per Ammo Box

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Flat Face View Manufacturers' Code Marking
13003NZ-G1 = Product Type Marking ID
YWW = Date Code Marking
e.g. 512 = Year 2015, Week 12.
8 = Assembly Site Code
XX = Batch Number



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	VCES	900	V
Collector-Emitter Voltage	V _{CEO}	530	V
Emitter-Base Voltage	V _{EBO}	10	V
Continuous Collector Current	lc	1.5	А
Peak Pulse Collector Current	Ісм	3	А
Continuous Base Current	Ι _Β	0.75	А
Peak Pulse Base Current	I _{BM}	1.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	PD	1.0	W
Thermal Resistance, Junction to Ambient Air	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	83.3	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C

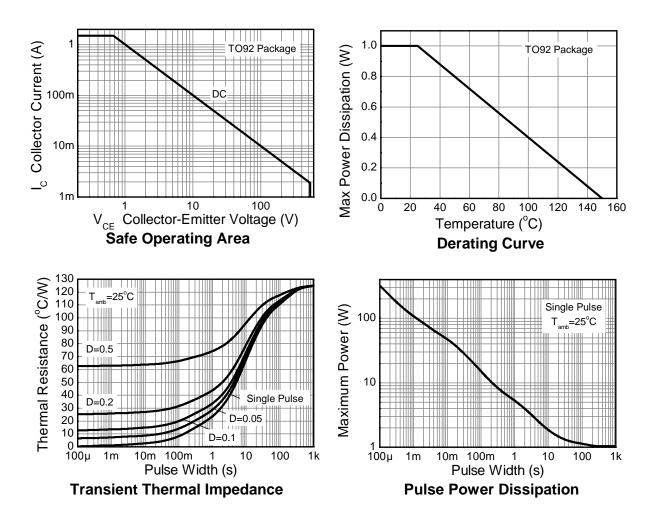
ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information (@T_A = +25°C, unless otherwise specified.)





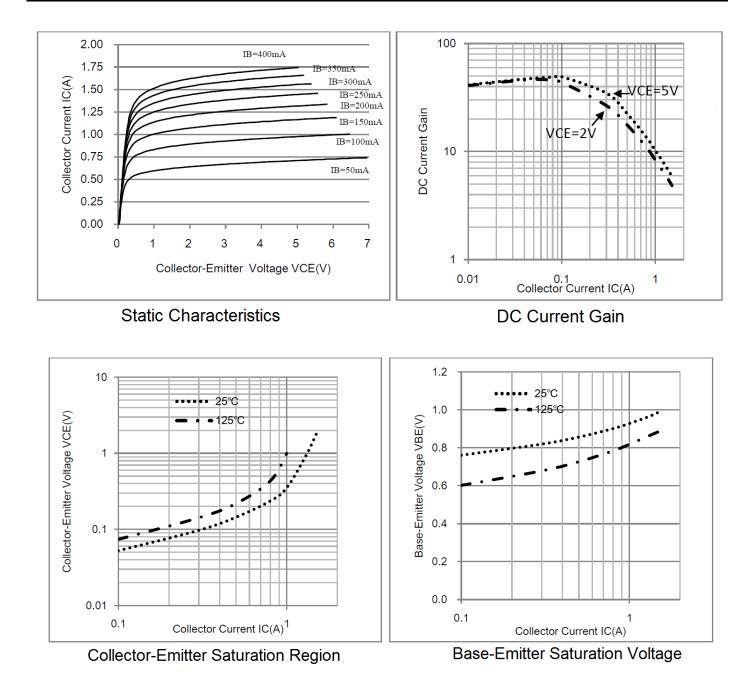
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	900	—	_	V	$I_{C} = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	530	—	—	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	10	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	—	—	10	μA	V _{CE} = 900V
DC Current Transfer Static Ratio (Note 6)	h _{FE}	15 5	17 —	30 25	—	$I_{C} = 0.5A, V_{CE} = 2V$ $I_{C} = 1.0A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(SAT)}	—	0.17 0.30	0.3 0.4	V	$I_{C} = 0.5A, I_{B} = 0.1A$ $I_{C} = 1A, I_{B} = 0.25A$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(SAT)}	—		1.0 1.2	V	$I_{C} = 0.5A, I_{B} = 0.1A$ $I_{C} = 1A, I_{B} = 0.25A$
Transition Frequency	fT	4	—	—	MHz	$I_{C} = 0.1A, V_{CE} = 10V$
Turn-on Time with Resistive Load	ton	—	—	1		$I_{C} = 1A, V_{CC} = 125V, I_{B1} = 0.2A,$ $I_{B2} = -0.2A, t_{p} = 25\mu s$
Storage Time with Resistive Load	ts	—	—	3.5	μs	
Fall Time with Resistive Load	tF	—	—	0.65		182 – 10.27, ip – 20µ8

Note: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



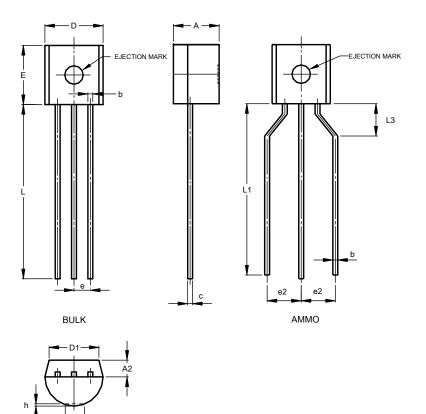
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



1						
ТО92 Туре С						
Dim	Min	Тур				
Α	3.30	3.70	-			
A2	1.00	1.40	-			
b	0.36	0.76	-			
c	0.32	0.51	-			
D	4.40	4.80	-			
D1	3.430	-	-			
Е	4.30	4.70	-			
е	-	-	1.27			
e2	-	-	2.54			
h	0.00	0.38	-			
L	12.50	15.50	-			
L1	12.50	14.50	-			
L3	2.50	4.00	-			
Ø	-	1.60	-			
All Dimensions in mm						

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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